## 1. General description

XC7SH08 is a high-speed Si-gate CMOS device. It provides a 2-input AND function.

## 2. Features

- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- SOT353-1 and SOT753 package options
- ESD protection:
  - HBM JESD22-A114E: exceeds 2000 V
  - MM JESD22-A115-A: exceeds 200 V
  - CDM JESD22-C101C: exceeds 1000 V
- Specified from –40 °C to +125 °C

## 3. Ordering information

#### Table 1.Ordering information

Type number	Package	Package						
	Temperature range	Name	Description	Version				
XC7SH08GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
XC7SH08GV	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753				

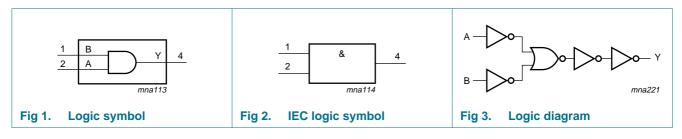
# nexperia

## 4. Marking

Table 2.   Marking codes	
Type number	Marking <sup>[1]</sup>
XC7SH08GW	fE
XC7SH08GV	f08

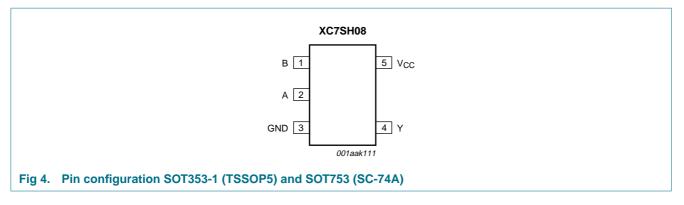
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



## 6. Pinning information

## 6.1 Pinning



## 6.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
В	1	data input
A	2	data input
GND	3	ground (0 V)
Y	4	data output
V <sub>CC</sub>	5	supply voltage

# 7. Functional description

#### Table 4.Function table

*H* = *HIGH* voltage level; *L* = *LOW* voltage level

Inputs	Output	
Α	В	Y
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V	-20	-	mA
Ι <sub>ΟΚ</sub>	output clamping current	$V_{O}$ < -0.5 V or $V_{O}$ > $V_{CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
I <sub>O</sub>	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I <sub>CC</sub>	supply current		-	75	mA
I <sub>GND</sub>	ground current		-75	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \ ^{\circ}C$ to +125 $^{\circ}C$	[2] _	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For both TSSOP5 and SC-74A packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

## 9. Recommended operating conditions

#### Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		2.0	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC}$ = 3.3 V $\pm$ 0.3 V	-	-	100	ns/V
		$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	-	-	20	ns/V

# **10. Static characteristics**

#### Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		_40 °C	to +85 °C	<b>−40</b> °C	to +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
VIH	HIGH-level	$V_{CC} = 2.0 V$	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V <sub>CC</sub> = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V <sub>CC</sub> = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O}$ = –50 $\mu\text{A};$ $V_{CC}$ = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O}$ = –50 $\mu A;$ $V_{CC}$ = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		$I_{O}$ = –50 $\mu A;$ $V_{CC}$ = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_{O}$ = -8.0 mA; $V_{CC}$ = 4.5 V	3.94	-	-	3.8	-	3.70	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = 50 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 50 \ \mu A; \ V_{CC} = 3.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 50 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O}$ = 4.0 mA; $V_{CC}$ = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		$I_{O}$ = 8.0 mA; $V_{CC}$ = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
l <sub>l</sub>	input leakage current	$V_I = 5.5 V \text{ or GND};$ $V_{CC} = 0 V \text{ to } 5.5 V$	-	-	0.1	-	1.0	-	2.0	μA
I <sub>CC</sub>	supply current		-	-	1.0	-	10	-	40	μΑ
CI	input capacitance		-	1.5	10	-	10	-	10	pF

# **11. Dynamic characteristics**

#### Table 8.Dynamic characteristics

GND = 0 V. For test circuit see Figure 6.

Symbol	Parameter	Conditions		25 °C		<b>−40 °C to +85 °C</b>		–40 °C to +125 °C		Unit	
				Min	Тур	Max	Min	Max	Min	Max	
t <sub>pd</sub> propagation delay	propagation delay	A and B to Y; see <u>Figure 5</u>	<u>[1]</u>								
		$V_{CC}$ = 3.0 V to 3.6 V	[2]								
		C <sub>L</sub> = 15 pF		-	4.6	8.8	1.0	10.5	1.0	12.0	ns
		$C_L = 50 \text{ pF}$		-	6.5	12.3	1.0	14.0	1.0	16.0	ns
		$V_{CC}$ = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	3.2	5.9	1.0	7.0	1.0	8.0	ns
		$C_L = 50 \text{ pF}$		-	4.6	7.9	1.0	9.0	1.0	10.5	ns
C <sub>PD</sub>	power dissipation capacitance	per buffer; $C_L = 50 \text{ pF}; \text{ f} = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	<u>[4]</u>	-	17	-	-	-	-	-	pF

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[2] Typical values are measured at  $V_{CC} = 3.3$  V.

[3] Typical values are measured at  $V_{CC}$  = 5.0 V.

[4]  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D$  ( $\mu$ W).

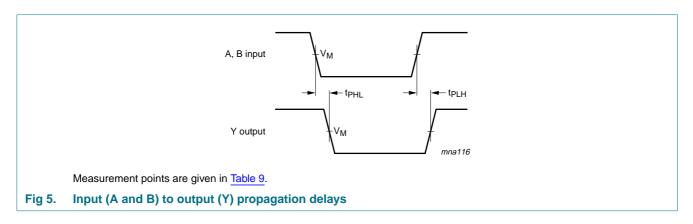
 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} + \Sigma(C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$ 

 $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz;

 $C_L$  = output load capacitance in pF;

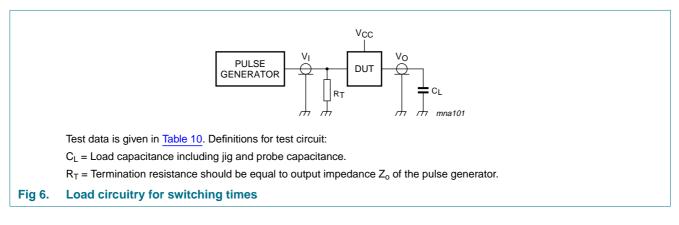
 $V_{CC}$  = supply voltage in Volts

# 12. Waveforms



#### Table 9.Measurement point

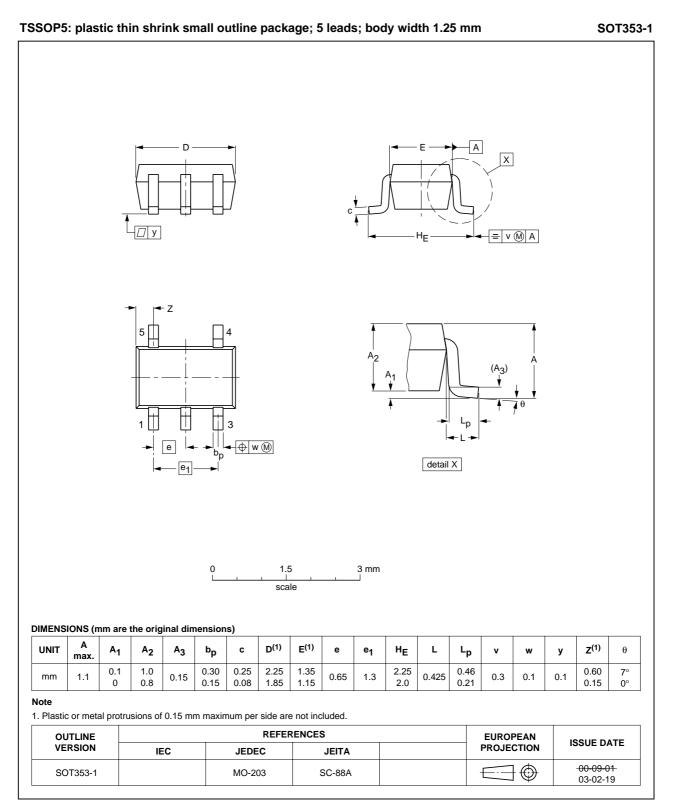
Туре	Input		Output	
	VI	V <sub>M</sub>	V <sub>M</sub>	
XC7SH08	GND to V <sub>CC</sub>	$0.5 \times V_{CC}$	$0.5  imes V_{CC}$	



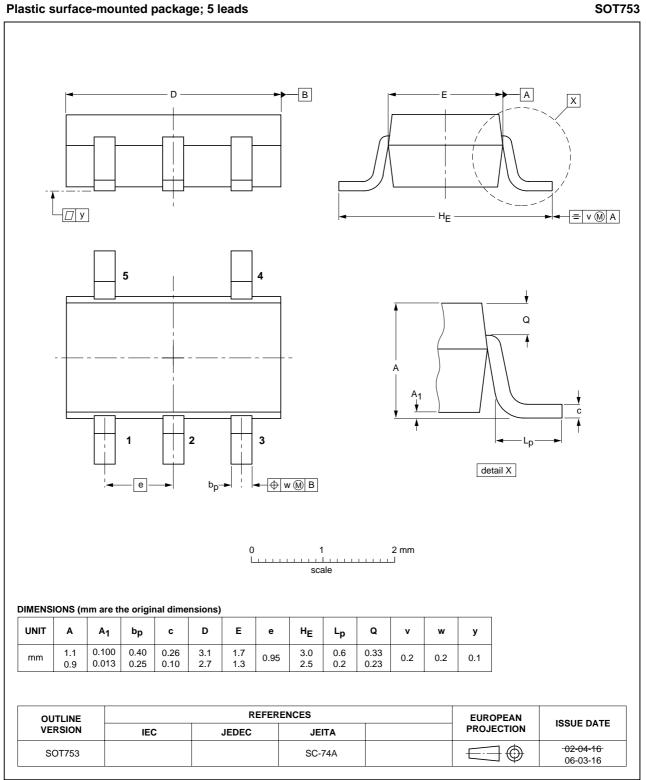
#### Table 10. Test data

Туре	Input		Load	Test
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	
XC7SH08	V <sub>CC</sub>	≤ 3.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>

## 13. Package outline



#### Fig 7. Package outline SOT353-1 (TSSOP5)



#### Plastic surface-mounted package; 5 leads

Package outline SOT753 (SC-74A) Fig 8.

# 14. Abbreviations

Table 11.	Abbreviations
Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 15. Revision history

Table 12. Revision history									
Document ID	Release date	Data sheet status	Change notice	Supersedes					
XC7SH08_1	20090901	Product data sheet	-	-					

# **16. Legal information**

## 16.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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